NSN 5961-01-031-0134

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View Online at https://aerobasegroup.com/nsn/5961-01-031-0134 **Inclosure Material:** Ceramic **Overall Length:** 0.225 inches **Overall Height:** 0.225 inches **Overall Width:** 0.355 inches **End Application:** Instrument landing system (ils) **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 8.00 amperes all primaries **Power Rating Per Characteristic:** 75.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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